## NSN 5961-00-415-6035

No Fiig: A110a0

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View Online at https://aerobasegroup.com/nsn/5961-00-415-6035 **Inclosure Material:** Metal **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.220 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-71 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 5.0 emitter to base voltage, dc all transistor and 60.0 collector to base voltage, dc all transistor and 60.0 collector to emitter voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector absolute all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead **Specification Data:** 80131-release5128 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**